Yanghui Liu

List of Publications by Year in descending order

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		394421	434195
34	1,815	19	31
papers	citations	h-index	g-index
35	35	35	2142
all docs	docs citations	times ranked	citing authors

Улисниц Ци

#	Article	IF	CITATIONS
1	Freestanding Artificial Synapses Based on Laterally Protonâ€Coupled Transistors on Chitosan Membranes. Advanced Materials, 2015, 27, 5599-5604.	21.0	352
2	Protonâ€Conducting Graphene Oxideâ€Coupled Neuron Transistors for Brainâ€Inspired Cognitive Systems. Advanced Materials, 2016, 28, 3557-3563.	21.0	226
3	Stretchable elastic synaptic transistors for neurologically integrated soft engineering systems. Science Advances, 2019, 5, eaax4961.	10.3	191
4	Lowâ€Voltage, Optoelectronic CH ₃ NH ₃ PbI _{3â~'} <i>_x</i> Cl <i>_x</i> Memory with Integrated Sensing and Logic Operations. Advanced Functional Materials, 2018, 28, 1800080.	14.9	190
5	Flexible Metal Oxide/Graphene Oxide Hybrid Neuromorphic Transistors on Flexible Conducting Graphene Substrates. Advanced Materials, 2016, 28, 5878-5885.	21.0	144
6	Short-Term Synaptic Plasticity Regulation in Solution-Gated Indium–Gallium–Zinc-Oxide Electric-Double-Layer Transistors. ACS Applied Materials & Interfaces, 2016, 8, 9762-9768.	8.0	81
7	Flexible Sensory Platform Based on Oxide-based Neuromorphic Transistors. Scientific Reports, 2015, 5, 18082.	3.3	70
8	Lowâ€₽ower Complementary Inverter with Negative Capacitance 2D Semiconductor Transistors. Advanced Functional Materials, 2020, 30, 2003859.	14.9	58
9	Dynamically Reconfigurable Shortâ€Term Synapse with Millivolt Stimulus Resolution Based on Organic Electrochemical Transistors. Advanced Materials Technologies, 2019, 4, 1900471.	5.8	57
10	Flexible Proton-Gated Oxide Synaptic Transistors on Si Membrane. ACS Applied Materials & Interfaces, 2016, 8, 21770-21775.	8.0	55
11	Solution-Processed Chitosan-Gated IZO-Based Transistors for Mimicking Synaptic Plasticity. IEEE Electron Device Letters, 2014, 35, 280-282.	3.9	48
12	Proton conducting sodium alginate electrolyte laterally coupled low-voltage oxide-based transistors. Applied Physics Letters, 2014, 104, 133504.	3.3	46
13	Laterally Coupled Dual-Gate Oxide-Based Transistors on Sodium Alginate Electrolytes. IEEE Electron Device Letters, 2014, 35, 1257-1259.	3.9	42
14	Multi-gate synergic modulation in laterally coupled synaptic transistors. Applied Physics Letters, 2015, 107, .	3.3	32
15	Low-Cost pH Sensors Based on Low-Voltage Oxide-Based Electric-Double-Layer Thin Film Transistors. IEEE Electron Device Letters, 2014, 35, 482-484.	3.9	28
16	Bienenstock–Cooper–Munro Learning Rule Realized in Polysaccharide-Gated Synaptic Transistors with Tunable Threshold. ACS Applied Materials & Interfaces, 2020, 12, 50061-50067.	8.0	25
17	Transient Characteristics for Proton Gating in Laterally Coupled Indium–Zinc-Oxide Transistors. ACS Applied Materials & Interfaces, 2015, 7, 6205-6210.	8.0	23
18	Extended-gate-type IGZO electric-double-layer TFT immunosensor with high sensitivity and low operation voltage. Applied Physics Letters, 2016, 109, .	3.3	21

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#	Article	IF	CITATIONS
19	Linear Classification Function Emulated by Pectinâ€Based Polysaccharideâ€Gated Multiterminal Neuron Transistors. Advanced Functional Materials, 2021, 31, 2102015.	14.9	19
20	Steep Slope p-type 2D WSe <inf>2</inf> Field-Effect Transistors with Van Der Waals Contact and Negative Capacitance. , 2018, , .		16
21	Tunable Schottky barriers in ultrathin black phosphorus field effect transistors via polymer capping. 2D Materials, 2019, 6, 024001.	4.4	13
22	Laterally Coupled Synaptic Transistors Gated by Proton Conducting Sodium Alginate Films. IEEE Electron Device Letters, 2014, 35, 672-674.	3.9	12
23	Flexible Oxide-Based Thin-Film Transistors on Plastic Substrates for Logic Applications. Journal of Materials Science and Technology, 2015, 31, 171-174.	10.7	12
24	Bandgap Engineering of ZrGaO Films for Deep-Ultraviolet Detection. IEEE Electron Device Letters, 2021, 42, 895-898.	3.9	10
25	Improved air-stability of an organic–inorganic perovskite with anhydrously transferred graphene. Journal of Materials Chemistry C, 2018, 6, 8663-8669.	5.5	9
26	Low-Voltage Depletion-Load Inverter Using Solid-State Electrolyte Gated Oxide Transistors. IEEE Electron Device Letters, 2016, 37, 591-594.	3.9	8
27	Contact resistance reduction of carbon nanotube via through O ₂ plasma post-synthesis treatment. Journal of Materials Chemistry C, 2018, 6, 5039-5045.	5.5	7
28	Surface Passivation Performance of Atomic-Layer-Deposited Al2O3 on p-type Silicon Substrates. Journal of Materials Science and Technology, 2014, 30, 835-838.	10.7	5
29	Dopamine Detection Based on Low-Voltage Oxide Homojunction Electric-Double-Layer Thin-Film Transistors. IEEE Electron Device Letters, 2016, , 1-1.	3.9	5
30	Low-Temperature Solution-Processed Lu ₂ O ₃ Films for Deep-UV Photovoltaic Detectors With High Sensitivity. IEEE Electron Device Letters, 2022, 43, 1295-1298.	3.9	5
31	Proton gated oxide electric-double-layer transistors for full-swing low voltage inverter applications. RSC Advances, 2016, 6, 1053-1057.	3.6	3
32	Effect of Annealing Temperature on Solar-Blind Ultraviolet Photodetectors Based on Solution-Processed Scandium Oxide Films. IEEE Electron Device Letters, 2022, 43, 1507-1510.	3.9	2
33	Self-assembled transparent a-IGZO based TFTs for flexible sensing applications. , 2014, , .		0
34	n-type Polycrystalline Si Thick Films Deposited on SiNx-coated Metallurgical Grade Si Substrates. Journal of Materials Science and Technology, 2015, 31, 65-69.	10.7	0